Week 3 Lecture 8 Quiz: Phonon Scattering: Part I

ECE 656: Electronic Conduction In Semiconductors

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Purdue University, Fall 2013
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Answer the **multiple choice questions** below by choosing the **one, best answer**. Then **ask a question** about the lecture.

- 1) Compare the typical acoustic phonon (sound) velocity, v_s , to the average thermal velocity of electrons, v_h . Which of the following is true?
 - a) $v_S \approx v_{th}$.
 - b) $v_{S} < v_{th}$.
 - c) $v_{s} \ll v_{th}$.
 - d) $v_S > v_{th}$.
 - e) $v_s \gg v_{th}$.
- 2) Comparing optical and acoustic phonons near the center of the Brillouin zone, which of the following is true?
 - a) Optical phonon velocity **much less** than acoustic phonon velocity and optical phonon energy **much less** than acoustic phonon energy.
 - b) Optical phonon velocity **much less** than acoustic phonon velocity and optical phonon energy **much greater** than acoustic phonon energy.
 - c) Optical phonon velocity **much greater** than acoustic phonon velocity and optical phonon energy **much less** than acoustic phonon energy.
 - d) Optical phonon velocity **much greater** than acoustic phonon velocity and optical phonon energy **much greater** than acoustic phonon energy..
 - e) Optical phonon velocity **roughly equal** to acoustic phonon velocity and optical phonon energy **roughly equal** to acoustic phonon energy.
- 3) Which phonons are most responsible for **intravalley** scattering?
 - a) Longitudinal modes near the zone center.
 - b) Transverse modes near the zone center.
 - c) Longitudinal modes near the zone boundary.
 - d) Transverse modes near the zone boundary.
 - e) Both longitudinal and transverse modes near the zone center.

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- 4) What is "deformation potential" scattering?
 - a) Scattering by acoustic phonons that is due to the change in bandgap (or band edge) due to a change in lattice spacing.
 - b) Scattering by optical phonons that is due to the change in bandgap (or band edge) due to a change in lattice spacing.
 - c) Scattering by either acoustic or optical phonons that is due to the change in bandgap (or band edge) due to a change in lattice spacing.
 - d) Scattering by defects in the crystal.
 - e) Scattering by an electrostatic dipole in the crystal.

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- 5) Which of the following scattering mechanisms occur in GaAs but not in Si?
 - a) Acoustic deformation potential scattering.
 - b) Optical deformation potential scattering.
 - c) Ionized impurity scattering.
 - d) Polar optical phonon scattering.
 - e) None of the above.
- 6) What question do you have about this lecture?

Turn in to Prof. Lundstrom in class on Friday.